



STT01L10

SamHop Microelectronics Corp.

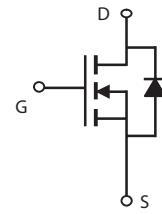
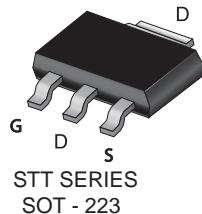
Ver 1.0

N-Channel Logic Level Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
VDSS	ID	RDS(ON) (mΩ) Max
100V	1.5A	310 @ VGS=10V
		350 @ VGS=4.5V

FEATURES

- Super high dense cell design for low RDS(ON).
- Rugged and reliable.
- Surface Mount Package.



ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Limit	Units
V_{DS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous ^{a d}	1.5	A
	$T_A=25^\circ\text{C}$	1.2	A
	$T_A=70^\circ\text{C}$		
I_{DM}	-Pulsed ^b	10	A
P_D	Maximum Power Dissipation ^a	3	W
	$T_A=25^\circ\text{C}$	1.9	W
	$T_A=70^\circ\text{C}$		
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

$R_\theta JA$	Thermal Resistance, Junction-to-Ambient ^a	42	$^\circ\text{C/W}$
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Details are subject to change without notice.

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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	100			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =80V , V _{GS} =0V			1	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V , V _{DS} =0V			±100	nA
ON CHARACTERISTICS						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	1	1.7	3	V
R _{D(S(ON))}	Drain-Source On-State Resistance	V _{GS} =10V , I _D =0.75A		230	310	m ohm
		V _{GS} =4.5V , I _D =0.7A		260	350	m ohm
g _{FS}	Forward Transconductance	V _{DS} =10V , I _D =0.75A		5.5		S
DYNAMIC CHARACTERISTICS ^c						
C _{iss}	Input Capacitance	V _{DS} =25V,V _{GS} =0V f=1.0MHz		480		pF
C _{oss}	Output Capacitance			28		pF
C _{rss}	Reverse Transfer Capacitance			20		pF
SWITCHING CHARACTERISTICS ^c						
t _{D(ON)}	Turn-On Delay Time	V _{DD} =50V I _D =0.75A V _{GS} =10V R _{GEN} = 6 ohm		9.3		ns
t _r	Rise Time			8.2		ns
t _{D(OFF)}	Turn-Off Delay Time			19.2		ns
t _f	Fall Time			9.2		ns
Q _g	Total Gate Charge	V _{DS} =50V,I _D =0.75A,V _{GS} =10V		8		nC
		V _{DS} =50V,I _D =0.75A,V _{GS} =4.5V		4.2		nC
Q _{gs}	Gate-Source Charge	V _{DS} =50V,I _D =0.75A, V _{GS} =10V		1		nC
Q _{gd}	Gate-Drain Charge			1.8		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
V _{SD}	Diode Forward Voltage	V _{GS} =0V,I _s =0.9A		0.8	1.2	V

Notes

- a.Surface Mounted on FR4 Board,t < 10sec.
- b.Pulse Test:Pulse Width < 300us, Duty Cycle < 2%.
- c.Guaranteed by design, not subject to production testing.
- d.Drain current limited by maximum junction temperature.

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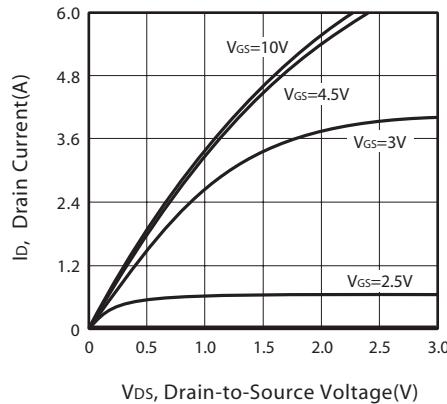


Figure 1. Output Characteristics

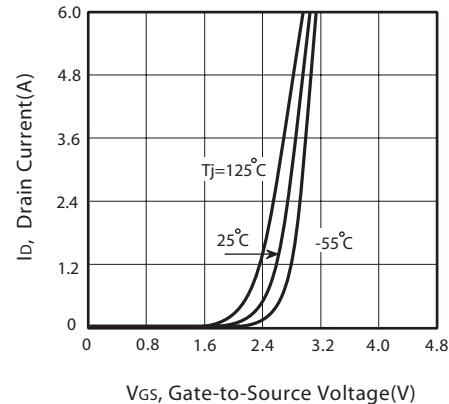


Figure 2. Transfer Characteristics

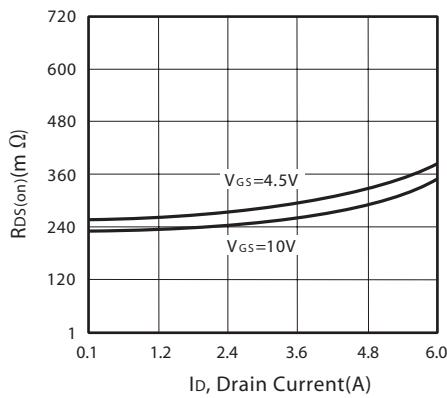


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

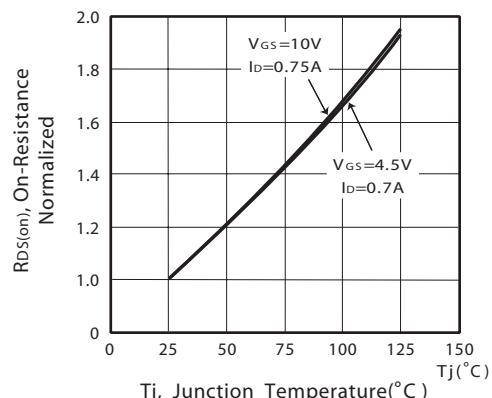


Figure 4. On-Resistance Variation with Drain Current and Temperature

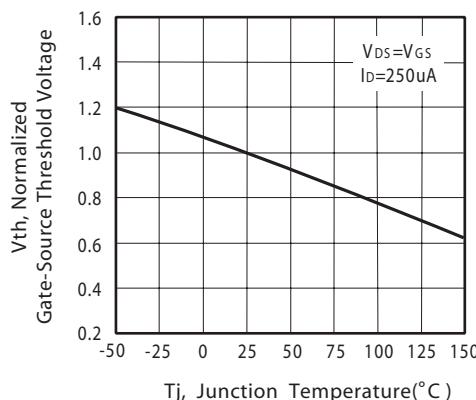


Figure 5. Gate Threshold Variation with Temperature

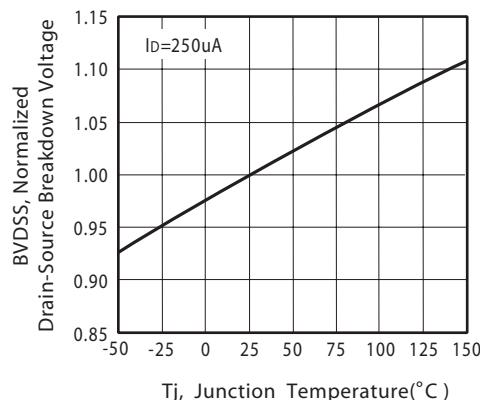
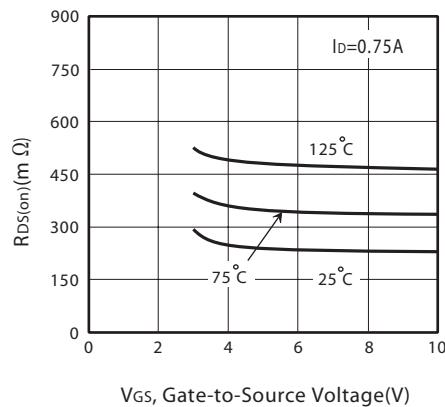


Figure 6. Breakdown Voltage Variation with Temperature

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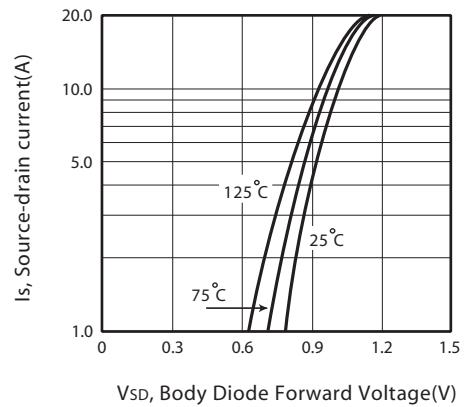
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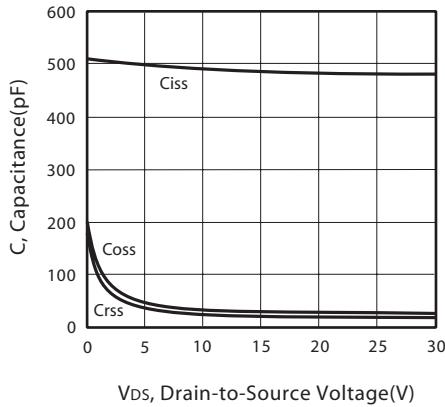
V_{GS}, Gate-to-Source Voltage(V)

Figure 7. On-Resistance vs. Gate-Source Voltage



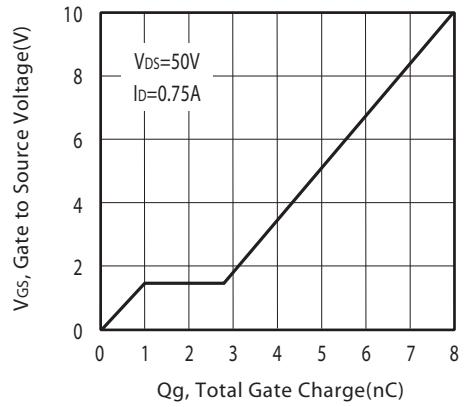
V_{SD}, Body Diode Forward Voltage(V)

Figure 8. Body Diode Forward Voltage Variation with Source Current



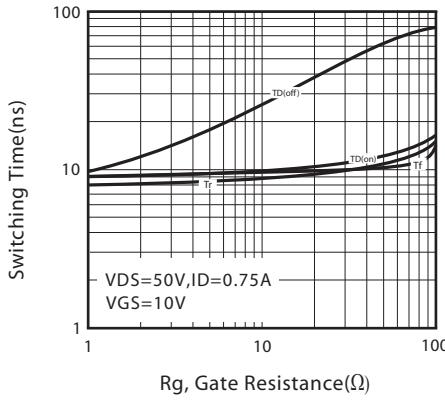
V_{DS}, Drain-to-Source Voltage(V)

Figure 9. Capacitance



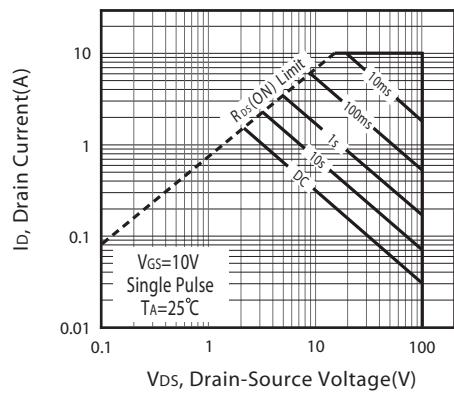
Q_g, Total Gate Charge(nC)

Figure 10. Gate Charge



R_g, Gate Resistance(Ω)

Figure 11. switching characteristics



V_{DS}, Drain-Source Voltage(V)

Figure 12. Maximum Safe Operating Area

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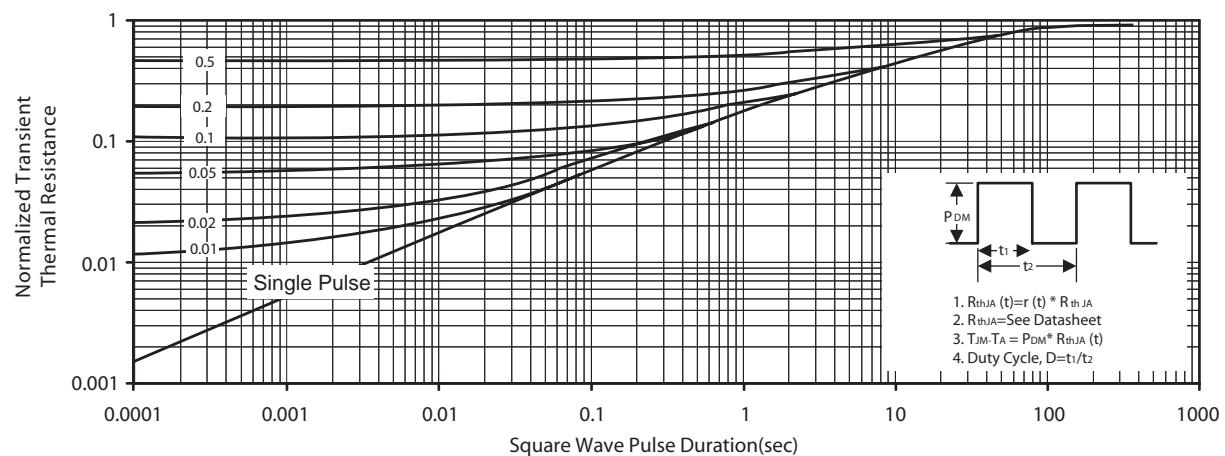
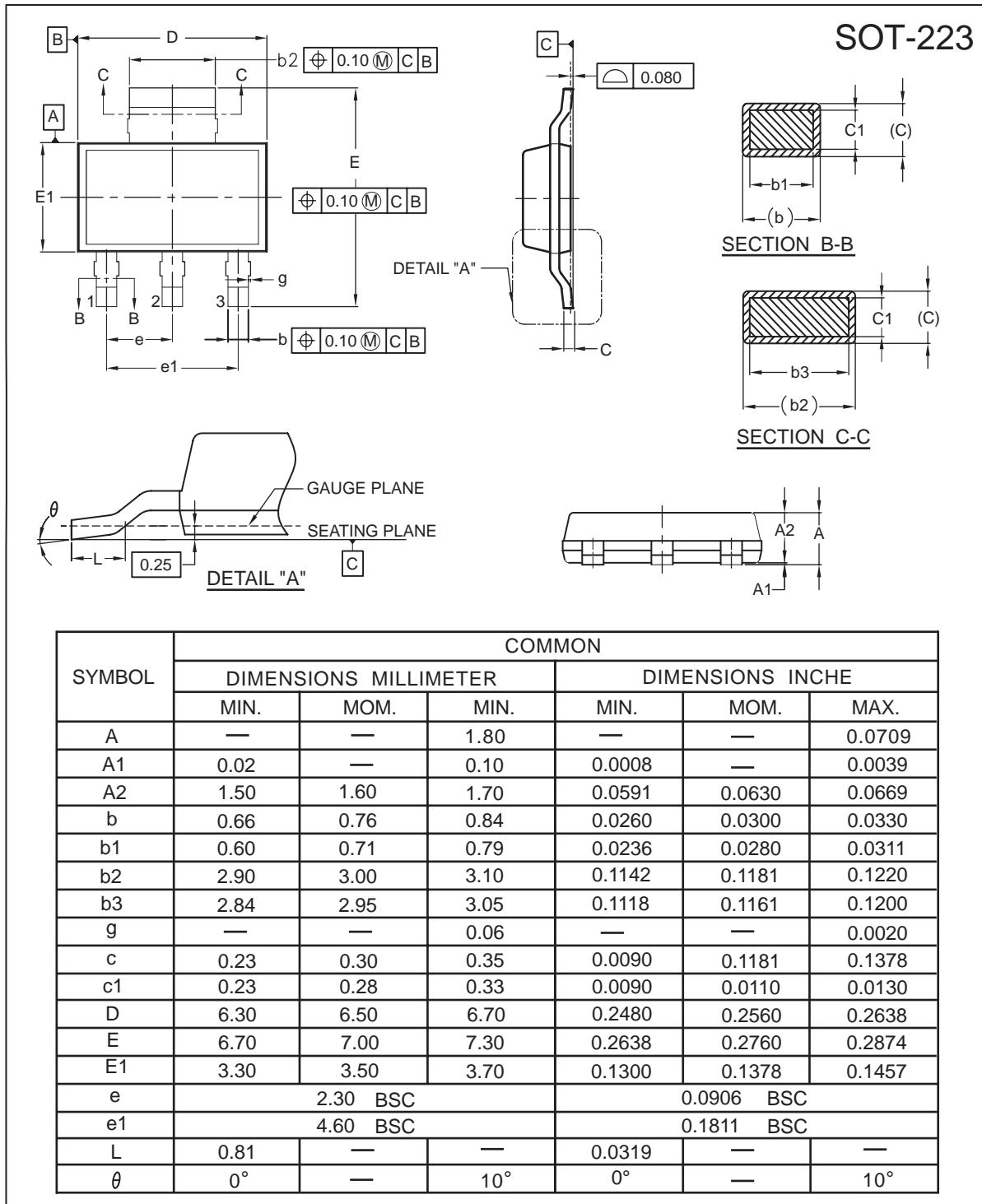


Figure 13. Normalized Thermal Transient Impedance Curve

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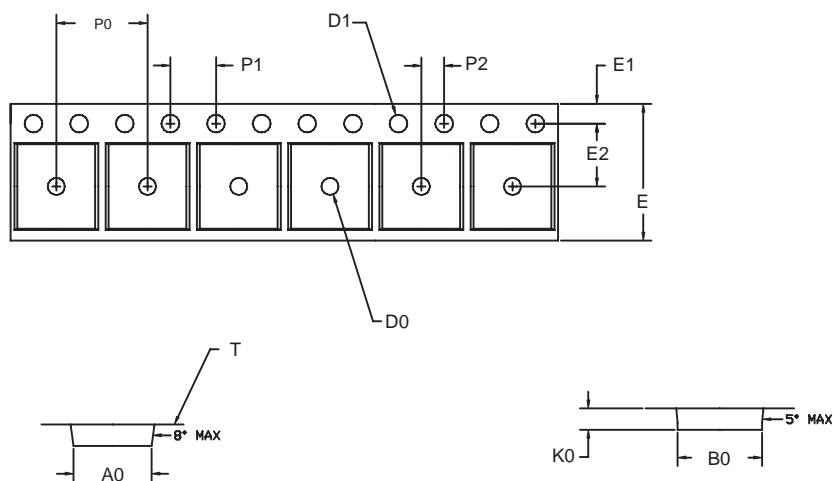
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SOT-223 Tape and Reel Data

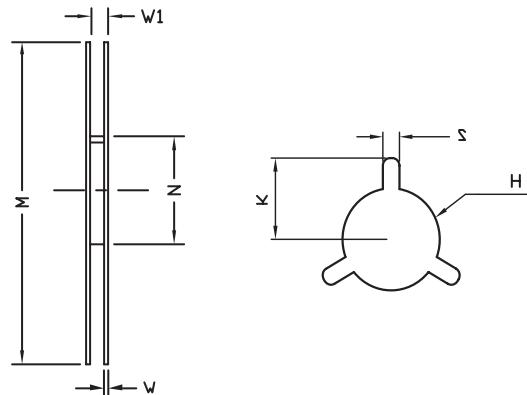
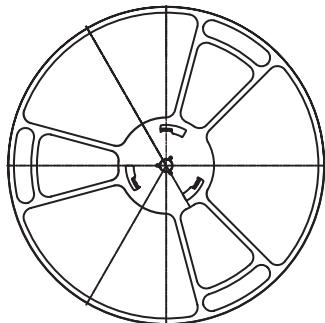
SOT-223 Carrier Tape



unit:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
---	6.83 ±0.1	7.42 ±0.1	1.88 ±0.1	1.50 + 0.25	1.60 + 0.1	12.0 + 0.3 - 0.1	1.75 ±0.1	5.50 ±0.5	8.0 ±0.1	4.00 ±0.1	2.00 ±0.05	0.292 ±0.02

SOT-223 Reel



UNIT:mm

REEL SIZE	M	N	W	W1	H	K	S	G	R	V
ø 330 ± 0.5	---	ø 97.0 ± 1.0	2.2	13.0 + 1.5	ø 13.0 + 0.5 - 0.2	10.6	2.0 ± 0.5	---	---	---

TOP MARKING DEFINITION

SOT-223

